NSN 5961-01-029-1022

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-029-1022 **Inclosure Material:** Metal **Overall Length:** 3.327 inches **Overall Diameter:** 1.100 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 1.240 inches and 1.250 inches **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1000.0 repetitive peak reverse voltage, peak total value **Current Rating Per Characteristic:** 250.00 amperes source cutoff current preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Test Data Document:** 10001-2887864 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 uninsulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No